NCE01P30K

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE01P30K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications. It is ESD protested.

General Features

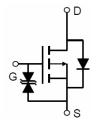
- V_{DS} =-100V,I_D =-30A
 - $R_{DS(ON)}$ <58m Ω @ V_{GS} =-10V (Typ:44m Ω)
 - $R_{DS(ON)}$ <65m Ω @ V_{GS} =-10V (Typ:48m Ω)
- Super high dense cell design
- Advanced trench process technology
- Reliable and rugged
- High density cell design for ultra low On-Resistance

Application

Portable equipment and battery powered systems

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE01P30K	NCE01P30K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-100	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	-30	Α
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	-21	А
Pulsed Drain Current	I _{DM}	-150	А
Maximum Power Dissipation	P _D	120	W
Derating factor		0.8	W/℃
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$

Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	R _{eJc}	1.25	°C/W
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NCE01P30K

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u>.</u>			•		
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-100	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-100V,V _{GS} =0V	-	_	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	_	±10	μA
On Characteristics (Note 3)	•		•	•		•
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =-250μA	-1.5	-1.9	-2.5	V
	Б	V _{GS} =-10V, I _D =-15A	-	44	58	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-15A	-	48	65	mΩ
Forward Transconductance	g Fs	V _{DS} =-50V,I _D =-10A	5	-	_	S
Dynamic Characteristics (Note4)	<u>.</u>			•		
Input Capacitance	C _{lss})/ 50)/)/ 0)/	-	3810	_	PF
Output Capacitance	Coss	V_{DS} =-50V, V_{GS} =0V, F=1.0MHz	-	93	_	PF
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIDZ	-	91	-	PF
Switching Characteristics (Note 4)	<u>.</u>			•		
Turn-on Delay Time	t _{d(on)}		-	17	-	nS
Turn-on Rise Time	t _r	V _{DD} =-50V,I _D =-15A	-	80	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10V, R_{GEN} =9.1 Ω	-	45	_	nS
Turn-Off Fall Time	t _f		-	65	_	nS
Total Gate Charge	Qg	V - 50VI - 45A	-	136	_	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-50V, I_{D} =-15A, V_{GS} =-10V	-	22	_	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	26	-	nC
Drain-Source Diode Characteristics	<u>.</u>			•		
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =-10A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	-30	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =-15A	-	90	_	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	70	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

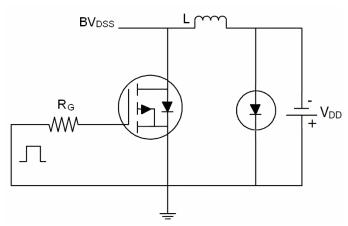
Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature.}$
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production

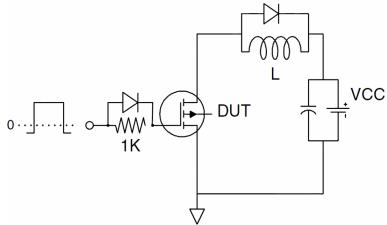


Test Circuit

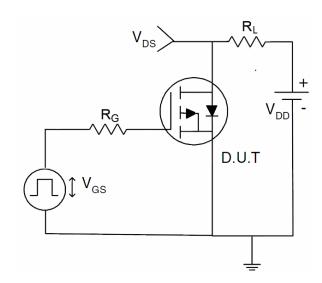
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



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Typical Electrical and Thermal Characteristics (Curves)

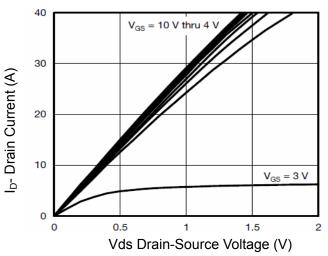


Figure 1 Output Characteristics

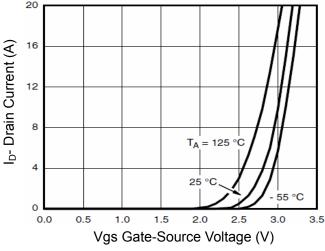


Figure 2 Transfer Characteristics

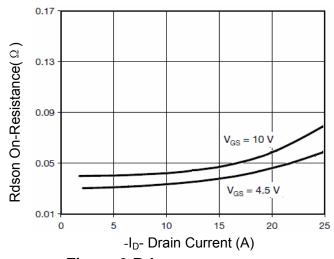


Figure 3 Rdson- Drain Current

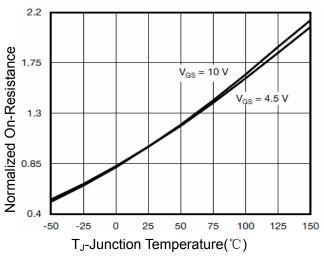


Figure 4 Rdson-JunctionTemperature

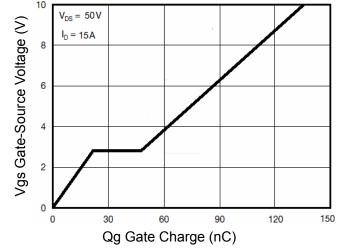


Figure 5 Gate Charge

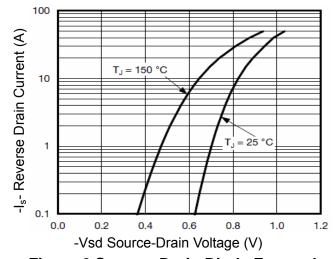
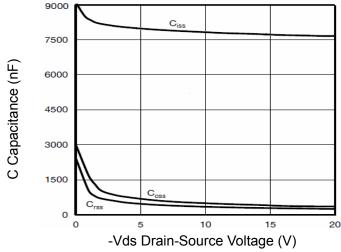


Figure 6 Source- Drain Diode Forward



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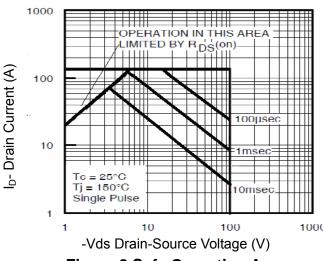


30 D- Drain Current (A) 20 10 100 150 T_C Case Temperature($^{\circ}C$)

40

Figure 7 Capacitance vs Vds

Figure 9 Drain Current vs Case Temperature



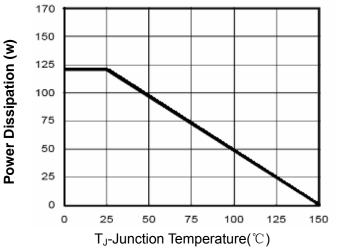
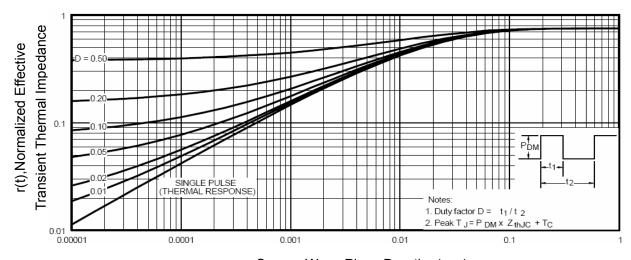


Figure 8 Safe Operation Area

Figure 10 Power De-rating



Square Wave Pluse Duration(sec)

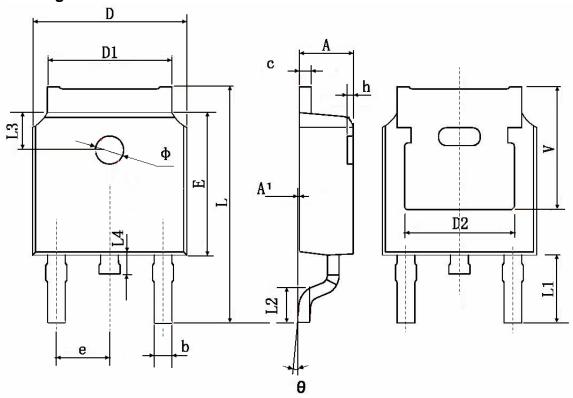
Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-252 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.83	OTYP.	0.190	TYP.	
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.90	2.900 TYP. 0.114		TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063	TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.35	0 TYP.	0.211 TYP.		



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